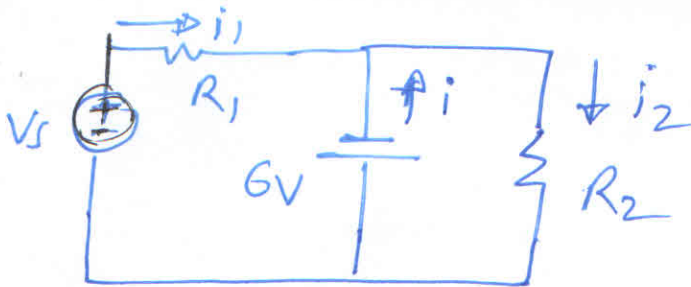


Q: 2(9)

Assume diode 'D' is ON



$$i_1 = \frac{V_s - (-6)}{R_1} = \frac{V_s + 6}{2000}$$

$$i_2 = \frac{-6}{R_2} = \frac{-6}{4000} = -1.5 \text{ mA}$$

For diode to be ON $i > 0$

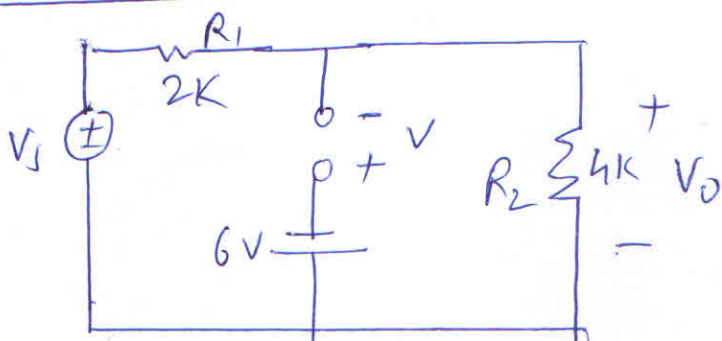
$$\begin{aligned} i &= i_2 - i_1 \\ &= -1.5 \times 10^{-3} - \left(\frac{V_s + 6}{2000} \right) \\ &= -1.5 \times 10^{-3} - \frac{V_s}{2000} - 3 \times 10^{-3} \\ &= \frac{-V_s}{2000} - 4.5 \times 10^{-3} \end{aligned}$$

$$\frac{-V_s}{2000} - 4.5 \times 10^{-3} > 0$$

$$\frac{V_s}{2000} + 4.5 \times 10^{-3} < 0$$

$$V_s < -9V \rightarrow (4)$$

For $V_s \geq -9V$ diode is OFF



$$\begin{aligned} V_o &= \frac{R_2}{R_1 + R_2} V_s = \frac{4K}{4K + 2K} V_s \\ &= \frac{2}{3} V_s \end{aligned}$$

By KVL:

$$V + V_o + 6 = 0$$

$$V = -V_o - 6$$

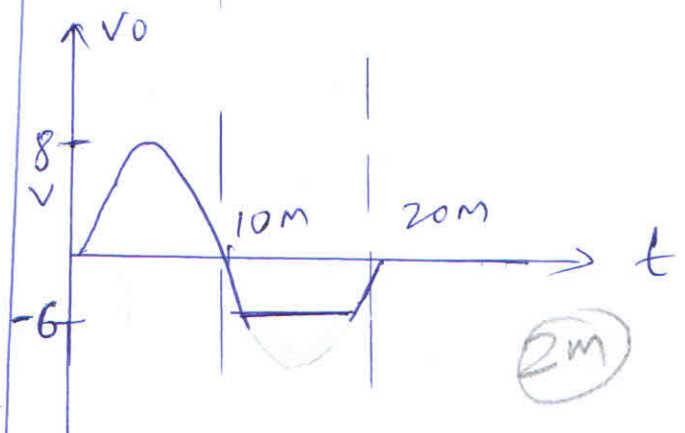
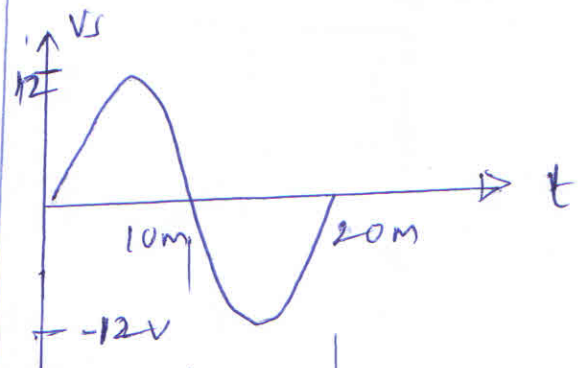
$$V = -\frac{2}{3} V_s - 6$$

$$V \leq 0$$

$$-\frac{2}{3} V_s - 6 \leq 0$$

$$\frac{2}{3} V_s + 6 \geq 0$$

$$V_s \geq -9V \rightarrow (4)$$



Q: 2(b)

$$V_E = V_{EB} = 0.7V \quad (2)$$

$$I_E = \frac{10 - 0.7}{2} = 4.65 \text{ mA} \quad (2)$$

$$\alpha = \frac{\beta}{\beta + 1} = \frac{100}{101} = 0.99$$

$$I_C = \alpha I_E = 4.6 \text{ mA} \quad (2)$$

$$\begin{aligned} V_C &= -10 + I_C R_C \\ &= -10 + 4.6 \times 1 \\ &= -5.4 \text{ V} \end{aligned} \quad (2)$$

$$I_B = I_E - I_C = 0.05 \text{ mA} \quad (2)$$

$$\begin{aligned} V_{CE} &= V_C - V_E = -5.4 - (0.7) \\ &= -6.1 \text{ V} \end{aligned}$$

$$V_{CE} < -0.2 \text{ V}$$

\therefore PNP BJT is in active region. (2)

OR

$$\begin{aligned} V_{CB} &= V_{EB} + V_{CE} \\ &= 0.7 + (-6.1) \\ &= -5.4 \text{ V} \end{aligned}$$

$$V_{CB} < V_{r}$$

\therefore Collector Base junction is Reverse biased.

\therefore PNP BJT is in active region.

Q: 3(a)

$$V_2 = \frac{30}{1500} \times 1000 = 20 \text{ V} \quad (2)$$

$$\begin{aligned} V_{GS} &= V_2 - I_D R_S \\ &= 20 \text{ V} - 2.5 \times 10^{-3} \times 5 \text{ K} \\ &= 7.5 \text{ V} \end{aligned} \quad (2)$$

$$\Rightarrow V_{GS} - V_t = 6.5 \text{ V}$$

$$\begin{aligned} V_D &= 30 - 3.5 \times 2.5 \\ &= 21.25 \text{ V} \end{aligned}$$

$$\begin{aligned} V_S &= I_D R_S = 2.5 \times 5 \\ &= 12.5 \text{ V} \end{aligned}$$

$$\therefore V_{DS} = 8.75 \text{ V} \quad (3)$$

$$V_{DS} > V_{GS} - V_t$$

\therefore transistor is in active/saturation region. (2)

$$\begin{aligned} K &= \frac{I_D}{(V_{GS} - V_t)^2} \\ &= \frac{2.5 \times 10^{-3}}{(6.5)^2} \\ &= 5.91 \times 10^{-5} \text{ A/V}^2 \end{aligned} \quad (3)$$

Q. 80 Ans 1 (b)

⑤ $V_1 - V_2 = 5i_o$ — ① — (1)

$5 + i_o = \frac{V_1 - V_2}{8} + i_o$ — ② — ~~2M~~

$3 + i_o = \frac{V_2 - V_1}{8} + \frac{V_2}{10}$ — ③ — ~~2M~~

$5 + \left(-\frac{V_1}{10}\right) = \frac{V_1 - V_2}{8} + i_o$

$i_o = -\frac{V_1}{10}$ — (4)

$i_o = 5 - \frac{V_1}{10} - \left(\frac{V_1 - V_2}{8}\right)$

$V_1 - V_2 = 5 \times \left(-\frac{V_1}{10}\right)$

$V_1 - V_2 = -\frac{V_1}{2}$

$V_1 \left[\frac{3}{2}\right] = V_2$

$3V_1 = 2V_2$

⑤ $3 + 5 - \frac{V_1}{10} - \left(\frac{V_1 - V_2}{8}\right) = \frac{V_2 - V_1}{8} + \frac{V_2}{10}$

$8 - \frac{V_1}{10} + \left(\frac{V_2 - V_1}{8}\right) = \frac{V_2 - V_1}{8} + \frac{V_2}{10}$

$80 = V_1 + V_2$

$240 = 2V_2 + 3V_2$

$5V_2 = 240$

$V_2 = \frac{48}{1} = 48$

$\therefore V_1 = \frac{2}{3} \times 48 = 32$

$V_1 = 32V$
 $V_2 = 48V$

~~7M~~ $\rightarrow 2M$
~~5M~~ $\rightarrow 2M$

Ques. 3(a)

$$V_2 = \frac{R_2}{R_1 + R_2} \cdot 30V = \frac{1}{1.5} \times 30 = 20V \quad (2m)$$

$$\begin{aligned} V_{GS} &= V_2 - I_D R_S \\ &= 20 - (2.5 \times 10^{-3}) (5 \times 10^3) \\ &\Rightarrow 20 - 12.5 \\ &= 7.5V \end{aligned} \quad (2m)$$

$$V_{GS} - V_t = 7.5 - 1 \Rightarrow 6.5V$$

$$V_S = I_S R_S = (2.5 \times 10^{-3}) \times 5K \Rightarrow 12.5V$$

$$\begin{aligned} V_D &= 30 - I_D R_D \\ &\Rightarrow 30 - (2.5 \times 10^{-3}) (3.5 \times 10^3) \\ &\Rightarrow 30 - 8.75 \end{aligned}$$

$$V_D \Rightarrow 21.25$$

hence

$$V_{DS} \Rightarrow 8.75V \quad (3m)$$

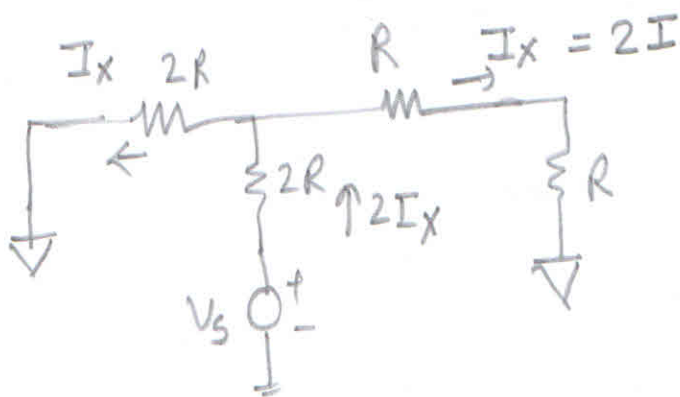
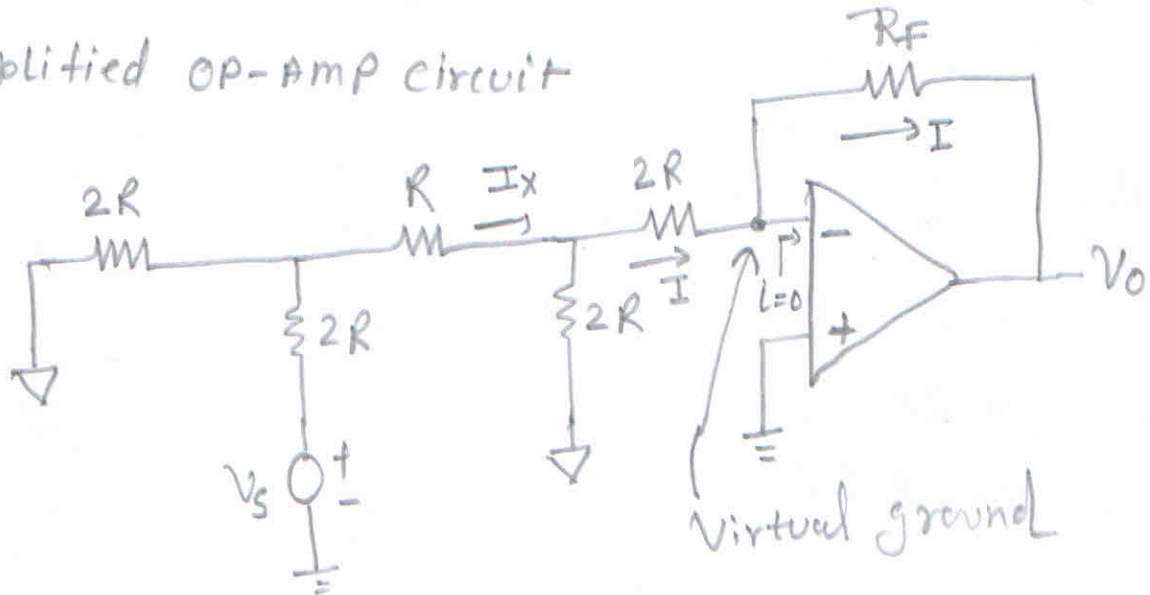
$V_{DS} \geq V_{GS} - V_t$; hence transistor in saturation/active region.

$$K = \frac{I_D}{(V_{GS} - V_t)^2} = \frac{2.5 \times 10^{-3}}{(6.5)^2} \quad (3m)$$

$$\begin{aligned} &\Rightarrow 0.0591 \text{ mA/V}^2 \\ &= 59.17 \mu\text{A/V}^2 \end{aligned}$$

Quey_3b(ii)

Simplitted OP-AMP circuit



$$2R \cdot 2I_X + 2RI_X = V_S$$

$$6RI_X = V_S$$

$$I_X = V_S/6R$$

$$I = V_S/12R$$

$$\rightarrow 8m$$

Q.1(a).

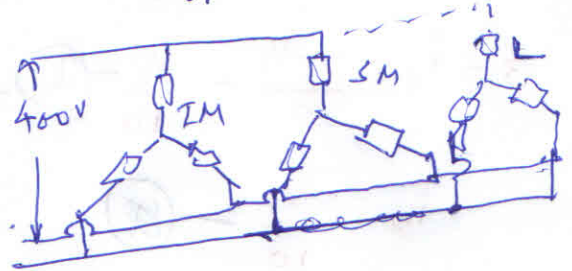
$$V_p = \frac{400}{\sqrt{3}} = 230.9 \text{ Volts}$$

$$Z_{ip} = 3 + j4 = 5 \angle 53.13^\circ \Omega, \quad I_p = \frac{V_p}{Z_{ip}} = 46.18 \angle -53.15^\circ \text{ A}$$

$$I_{ik} = I_{ip} = 46.18 \angle -53.15^\circ$$

$$I_{sl} = 100 \angle 31.79^\circ \text{ A}$$

$$I_e = I_{sl} + I_{ik} = 113.79 \angle 7.95^\circ = (112.7 + j15.74) \text{ Amp}$$



(a) $\phi = 7.95^\circ$, $\cos \phi = 0.9904$ (leading) (5)

(b) $P = \sqrt{3} \times 400 \times 113.79 \times \cos 7.95^\circ = 78 \times 10^3 \text{ Watts}$
 $Q = \sqrt{3} \times 400 \times 113.79 \times \sin 7.95^\circ = 10.9 \times 10^3 \text{ VAR}$ (5)

(c) $= \frac{231 \angle 0}{112.7 + j15.74} = (2.01 - j.28) \Omega = Z_{eq}$
 To have 0.8 p.f lagging
 $Z'_{eq} = (2.01 - j.28 + jX_L)$
 Inductor will be connected
 $\frac{(X_L - .28)}{2.01} = 0.75$
 $X_L = 1.787 = \omega L$
 $L = 0.005 \text{ Henry}$ (5)

80 Am 1 b

⑤ $V_1 - V_2 = 5 i_D$ — ① — (1)

$5 + i_D = \frac{V_1 - V_2}{8} + i_D$ — ② — 2M

$3 + i_D = \frac{V_2 - V_1}{8} + \frac{V_2}{10}$ — ③ — 2M

$i_D = -\frac{V_1}{10}$ — (4)

$5 + (-\frac{V_1}{10}) = \frac{V_1 - V_2}{8} + i_D$

$i_D = 5 - \frac{V_1}{10} - (\frac{V_1 - V_2}{8})$

$V_1 - V_2 = 5 \times (-\frac{V_1}{10})$

$V_1 - V_2 = -\frac{V_1}{2}$

$V_1 [\frac{3}{2}] = V_2$

$3V_1 = 2V_2$

⑤ $3 + 5 - \frac{V_1}{10} - (\frac{V_1 - V_2}{8}) = \frac{V_2 - V_1}{8} + \frac{V_2}{10}$

$8 - \frac{V_1}{10} + (\frac{V_2 - V_1}{8}) = \frac{V_2 - V_1}{8} + \frac{V_2}{10}$

$80 = V_1 + V_2$

$240 = 2V_2 + 3V_2$

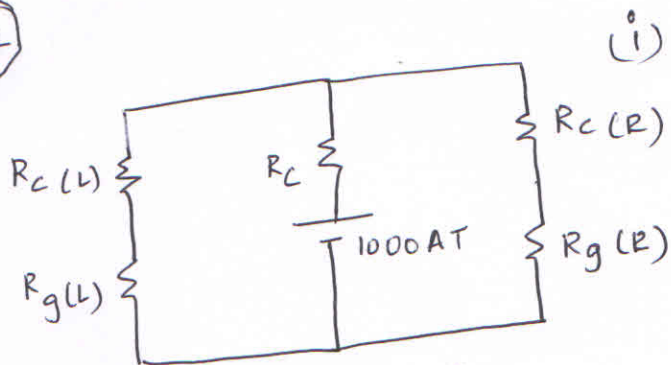
$5V_2 = 240$

$V_2 = \frac{48}{5} = 9.6$

$V_1 = 32V$ — 2M
 $V_2 = 48V$ — 2M

$V_1 = \frac{2}{3} \times 48 = 32$

Q4



$$R_c = \frac{10 \times 10^{-2}}{1000 \times 4\pi \times 10^{-7} \times 4 \times 10^{-4}} = 1.989 \times 10^5 \text{ AT/Wb.} \quad (2)$$

$$R_{c(L)} = \frac{29 \times 10^{-2}}{1000 \times 4\pi \times 10^{-7} \times 4 \times 10^{-4}} = 5.769 \times 10^5 \text{ AT/Wb.}$$

$$R_{g(L)} = \frac{1 \times 10^{-2}}{4\pi \times 10^{-7} \times 4 \times 10^{-4}} = 1.989 \times 10^7 \text{ AT/Wb.}$$

$$R_a = R_{c(L)} + R_{g(L)} = 20.47 \times 10^6 \text{ AT/Wb.} \quad (2)$$

$$R_{c(R)} = \frac{29.5 \times 10^{-2}}{1000 \times 4\pi \times 10^{-7} \times 4 \times 10^{-4}} = 5.869 \times 10^5 \text{ AT/Wb.}$$

$$R_{g(R)} = \frac{0.5 \times 10^{-2}}{4\pi \times 10^{-7} \times 4 \times 10^{-4}} = 9.947 \times 10^6 \text{ AT/Wb.}$$

$$R_b = R_{c(R)} + R_{g(R)} = 10.53 \times 10^6 \text{ AT/Wb.} \quad (2)$$

$$R_{\text{total}} = R_c + \frac{1}{1/R_a + 1/R_b} = 7.152 \times 10^6 \text{ AT/Wb.} \quad (1)$$

$$(ii) \phi_c = \frac{Ni}{R_{\text{total}}} = \frac{1000}{7.152 \times 10^6} = 139.82 \mu \text{Wb.} \quad (2)$$

$$\phi_a = \phi_c \frac{R_b}{R_a + R_b} = 139.82 \mu \frac{R_b}{R_a + R_b} = 47.49 \mu \text{Wb.} \quad (2)$$

$$\phi_b = \phi_c \frac{R_a}{R_a + R_b} = 92.32 \mu \text{Wb.} \quad (2)$$

$$(iii) B_a = \frac{\phi_a}{A_a} = \frac{47.49 \mu}{A_a} = \frac{47.49 \mu}{4 \times 10^{-4}} = 0.1187 \text{ T} \quad (1)$$

$$B_b = \frac{92.32 \mu}{4 \times 10^{-4}} = 0.2308 \text{ T.} \quad (1)$$